NSN 5961-01-471-7950

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-471-7950 **Inclosure Material:** Metal **Overall Length:** Between 0.140 inches and 0.180 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.056 inches and 0.075 inches **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 breakdown voltage, dc and 50.0 working peak reverse voltage **Current Rating Per Characteristic:** 4.00 amperes forward current, average preset and 200.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 81349-mil-prf19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/253 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0

Mil-std (military Standard):

spec.